



SGMNQ90540

40V, Power, Single N-Channel, PDFN Package, MOSFET

FEATURES

- Low On-State Resistance
- Low Total Gate Charge and Capacitance Losses
- Small Footprint (5×6mm²) for Compact Design
- Halogen-Free/RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNITS
Drain-to-Source Voltage	V _{DS}	40	V
Gate-to-Source Voltage	V _{GS}	±20	V
Drain Current ⁽¹⁾	I _D	T _A = +25°C	44
		T _A = +70°C	35
		T _C = +25°C	320
		T _C = +100°C	202
Drain Current (Pulse) ⁽²⁾	I _{DM}	900	A
Total Dissipation	P _D	T _A = +25°C	2.5
		T _A = +70°C	1.6
		T _C = +25°C	131
		T _C = +100°C	52
Avalanche Current ⁽³⁾	I _{AS}	97	A
Avalanche Energy ⁽³⁾	E _{AS}	470.45	mJ
Junction Temperature	T _J	+150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Lead Temperature (Soldering, 10s)		+260	°C

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

NOTES:

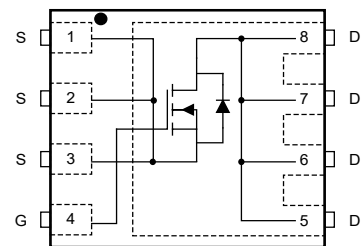
1. The current will be limited by PCB, thermal design and operating temperature.
2. t_{PLUSE} < 10µs
3. Parts are 100% tested at V_{GS} = 10V, I_L = 69A, E_{AS} = 238.05mJ

PRODUCT SUMMARY

R _{DS(on)} (TYP) V _{GS} = 10V	R _{DS(on)} (MAX) V _{GS} = 10V	I _D (MAX) T _C = +25°C
0.72mΩ	0.94mΩ	320A

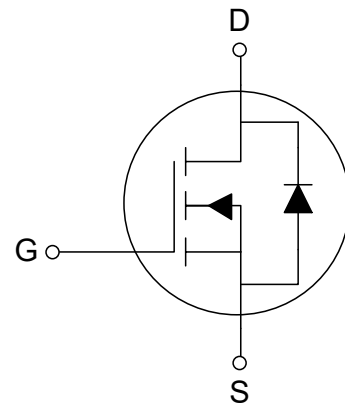
PIN CONFIGURATION

(TOP VIEW)



PDFN-5×6-8CL

EQUIVALENT CIRCUIT



APPLICATIONS

- Power Tool
- Brushless DC Motor Control
- Hotswap/In-Rush Current Management
- DC/DC Converters
- Power Load Switch and eFuse

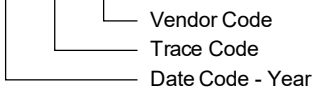
PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGMNQ90540	PDFN-5x6-8CL	-55°C to +150°C	SGMNQ90540TPDA8G/TR	SGM0T4 TPDA8 XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

XXXXX



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

THERMAL RESISTANCE MAXIMUM RATINGS

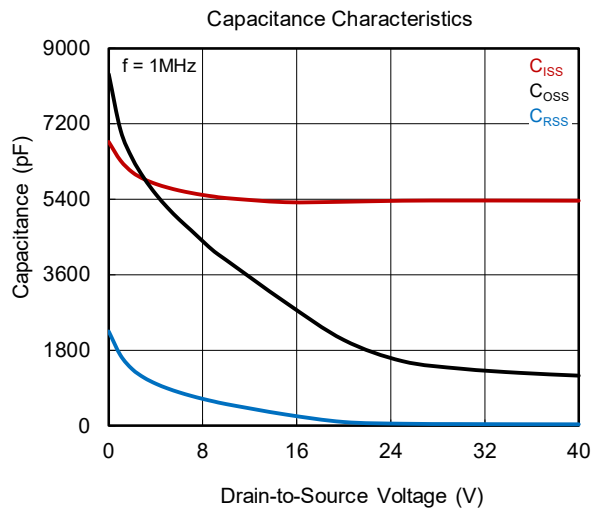
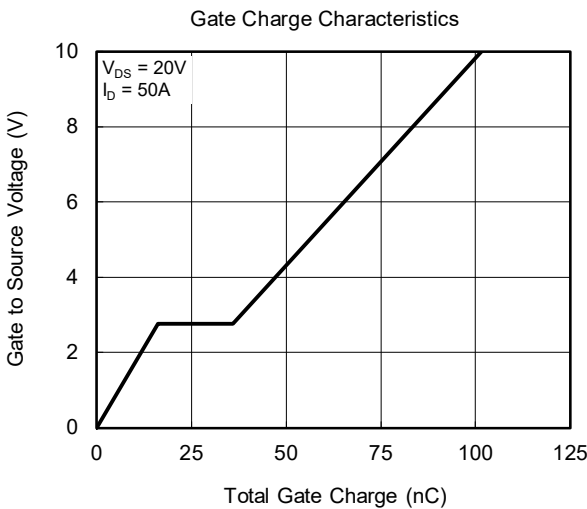
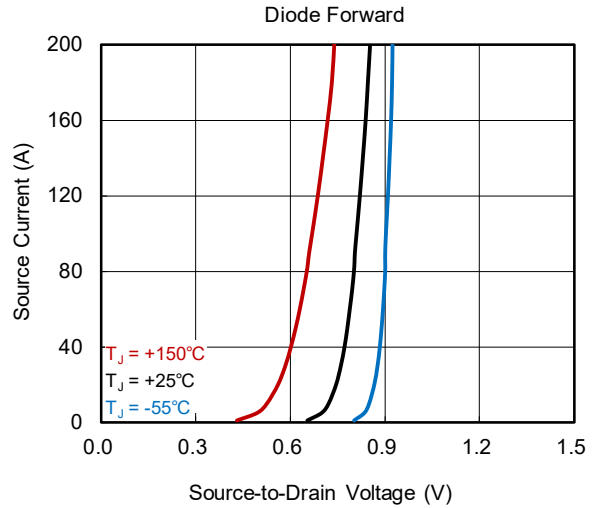
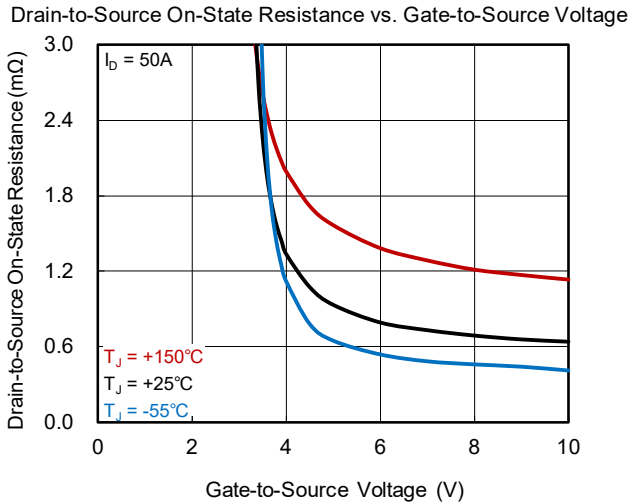
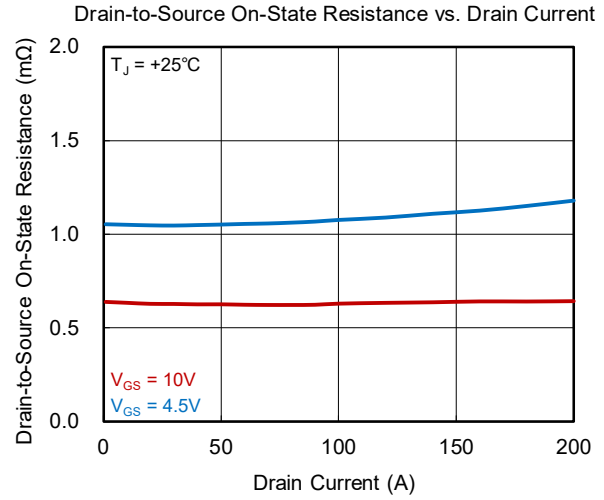
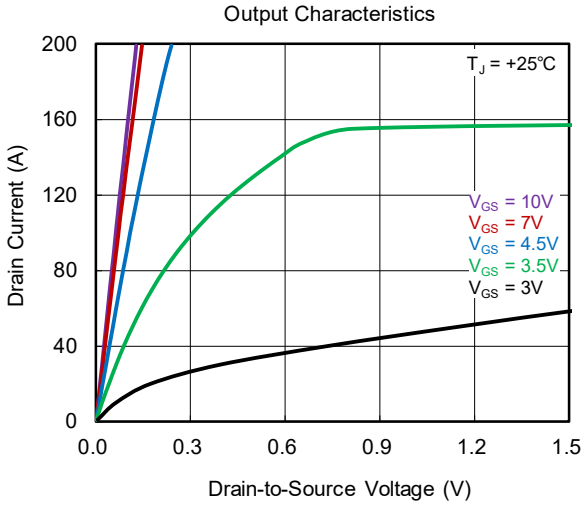
PARAMETER	SYMBOL	VALUE	UNITS
Junction-to-Ambient Thermal Resistance ⁽¹⁾	R _{θJA}	49	°C/W
Junction-to-Case Thermal Resistance	R _{θJC}	0.95	°C/W

NOTE: 1. R_{θJA} is determined with the device mounted on one square inch of copper pad, 2oz copper on FR4 board.

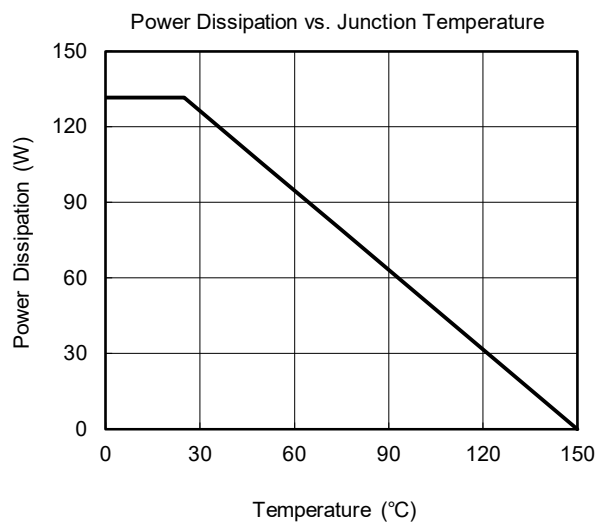
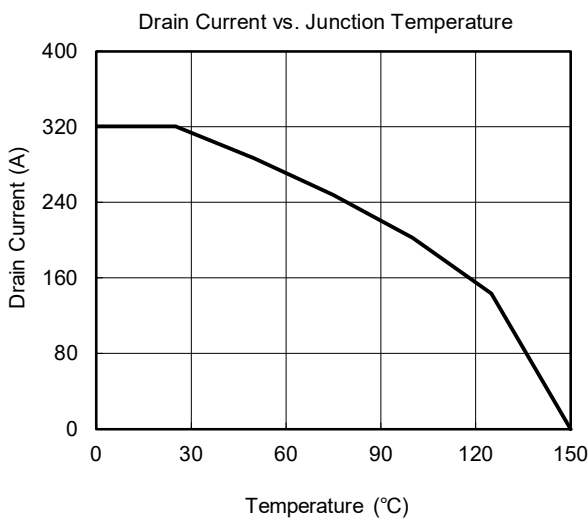
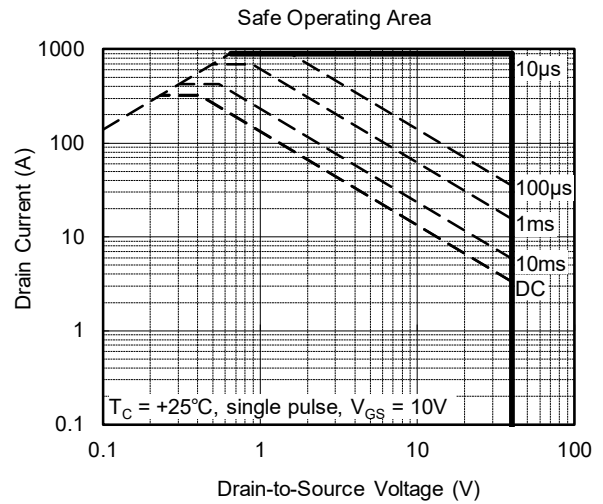
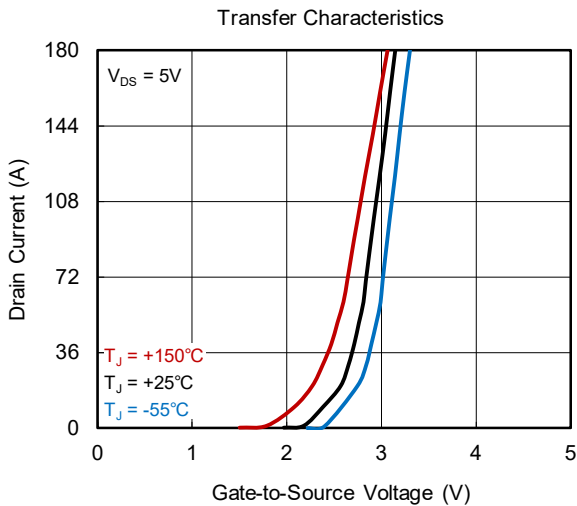
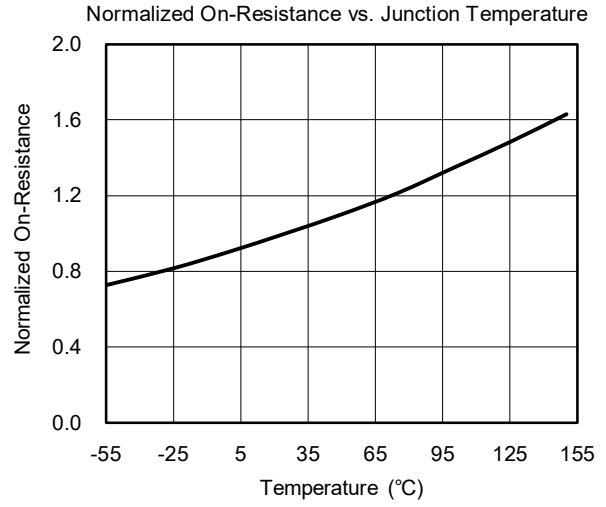
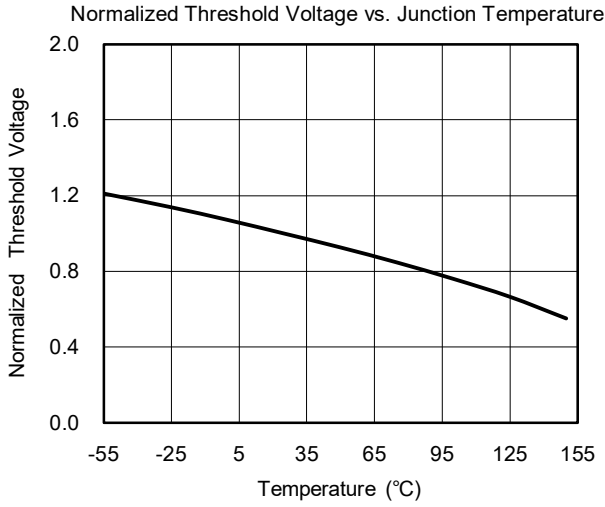
ELECTRICAL CHARACTERISTICS(T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Static OFF Characteristics						
Drain-to-Source Breakdown Voltage	V _{BR_DSS}	V _{GS} = 0V, I _D = 250μA	40			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0V, V _{DS} = 32V			10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
Static ON Characteristics						
Gate-to-Source Threshold Voltage	V _{GS_TH}	V _{GS} = V _{DS} , I _D = 250μA	1.2	1.6	2.2	V
Drain-to-Source On-State Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 50A		0.72	0.94	mΩ
		V _{GS} = 4.5V, I _D = 50A		1.05	1.47	
Forward Transconductance	g _{fs}	V _{DS} = 5V, I _D = 50A		103		S
Gate Resistance	R _G	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz		1.6		Ω
Diode Characteristics						
Diode Forward Voltage	V _{F_SD}	V _{GS} = 0V, I _S = 50A		0.7		V
Reverse Recovery Time	t _{RR}	V _{GS} = 0V, I _S = 50A, di/dt = 100A/μs		73		ns
Reverse Recovery Charge	Q _{RR}			125		nC
Dynamic Characteristics						
Input Capacitance	C _{ISS}	V _{GS} = 0V, V _{DS} = 25V, f = 1MHz		5385		pF
Output Capacitance	C _{OSS}			1562		
Reverse Transfer Capacitance	C _{RSS}			49		
Total Gate Charge	Q _g	V _{DS} = 20V, I _D = 50A	V _{GS} = 10V	102		nC
			V _{GS} = 4.5V	52		
Gate-to-Source Charge	Q _{GS}	V _{GS} = 4.5V, V _{DS} = 20V, I _D = 50A		16		nC
Gate-to-Drain Charge	Q _{GD}			20		
Switch Characteristics						
Turn-On Delay Time	t _{D_ON}	V _{GS} = 10V, V _{DS} = 20V, I _D = 50A, R _G = 3Ω		13		ns
Rise Time	t _r			52		
Turn-Off Delay Time	t _{D_OFF}			63		
Fall Time	t _f			78		

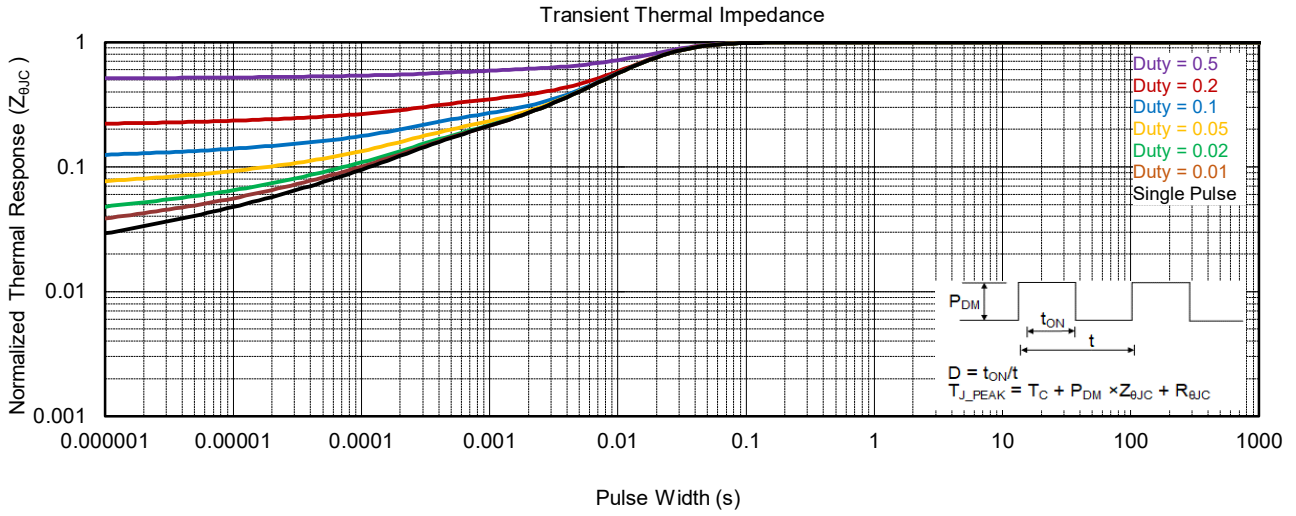
TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



REVISION HISTORY

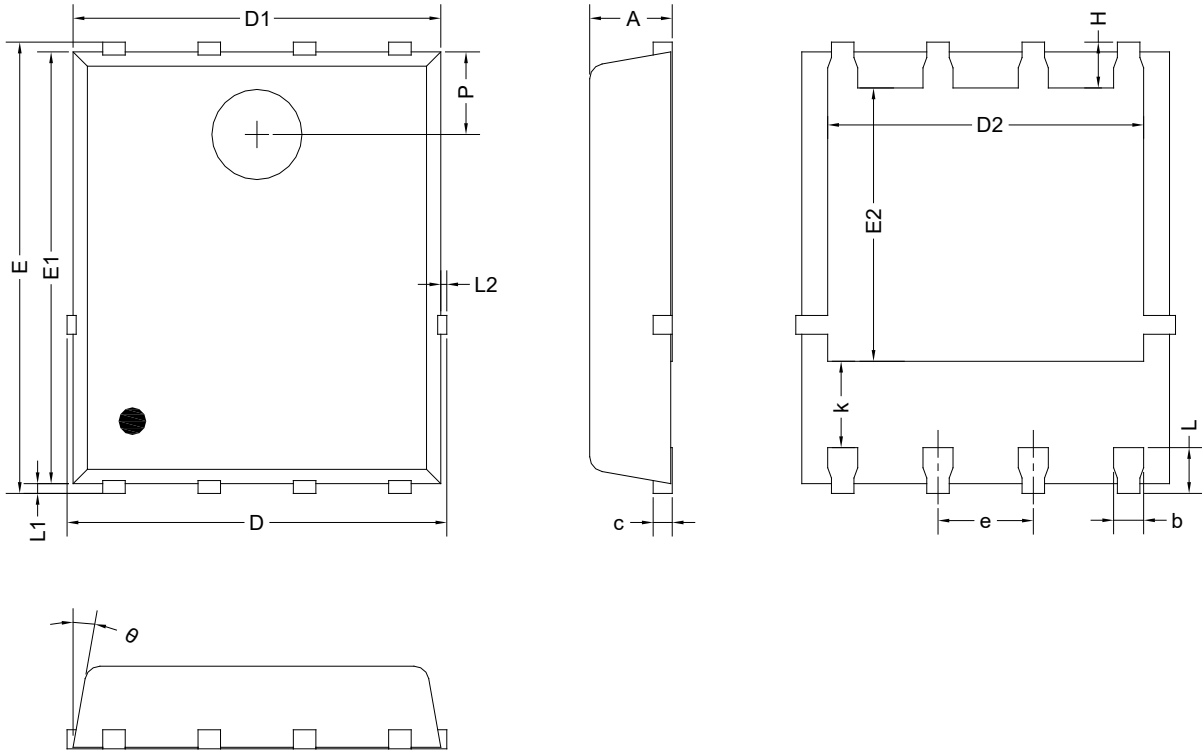
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (NOVEMBER 2024) to REV.A	Page
Changed from product preview to production data.....	All

PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

PDFN-5×6-8CL



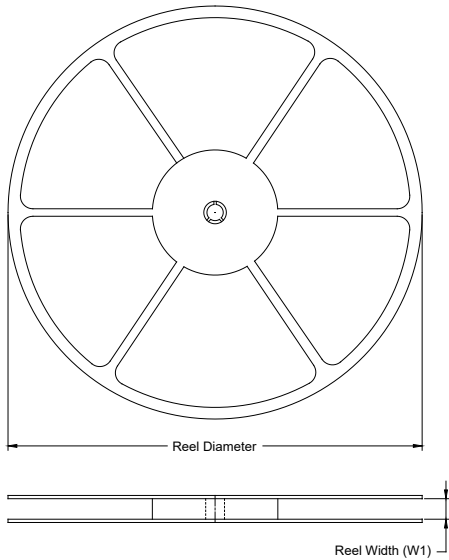
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	1.000	1.100	1.200
b	0.350	0.400	0.450
c	0.210	0.250	0.340
D	4.800	-	5.100
D1	4.800	4.900	5.000
D2	4.110	4.210	4.310
E	5.900	6.000	6.100
E1	5.700	5.750	5.800
E2	3.540	3.640	3.740
e	1.270 BSC		
H	0.510	0.610	0.710
k	1.100	-	-
L	0.510	0.610	0.710
L1	0.060	0.130	0.200
L2	-	-	0.100
P	1.000	1.100	1.200
θ	8°	10°	12°

NOTE: This drawing is subject to change without notice.

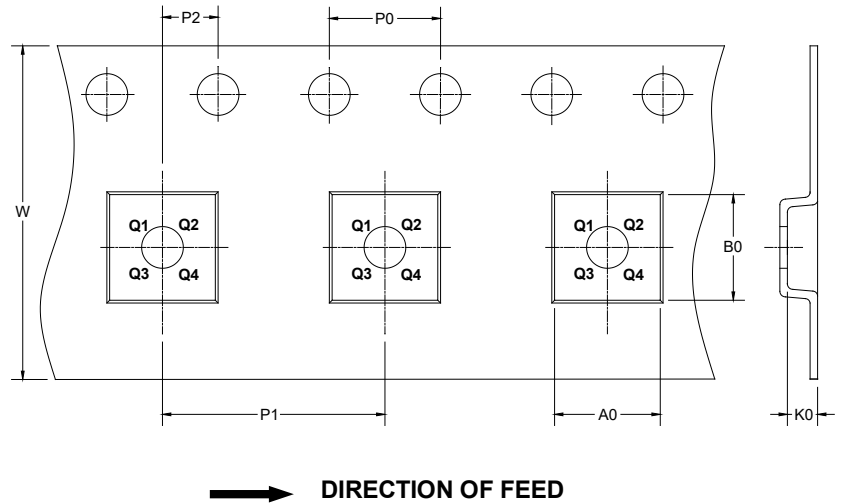
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

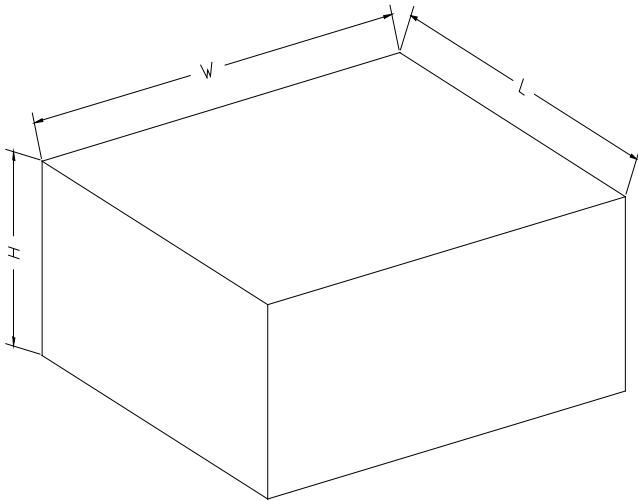
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
PDFN-5×6-8CL	13"	12.4	6.45	5.30	1.40	4.0	8.0	2.0	12.0	Q1

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002